

1 Characteristics

Table 2: Absolute ratings (limiting values)

Symbol	Parameter			Value	Unit
$I_{T(RMS)}$	RMS on-state current (full sine wave)	D ² PAK, TO-220AB	$T_C = 136\text{ }^{\circ}\text{C}$	8	A
		TO-220AB Ins.	$T_C = 123\text{ }^{\circ}\text{C}$		
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_J initial = $25\text{ }^{\circ}\text{C}$)	$f = 50\text{ Hz}$	$t_p = 20\text{ ms}$	80	A
		$f = 60\text{ Hz}$	$t_p = 16.7\text{ ms}$	84	
I^2t	I^2t value for fusing		$t_p = 10\text{ ms}$	42	A ² s
di/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \leq 100\text{ ns}$	$f = 50\text{ Hz}$	$T_J = 150\text{ }^{\circ}\text{C}$	50	A/ μs
V_{DSM} / V_{RSM}	Non repetitive surge peak off- state voltage	$t_p = 10\text{ ms}$	$T_J = 25\text{ }^{\circ}\text{C}$	$V_{DRM}/V_{RRM} + 100$	V
I_{GM}	Peak forward gate current	$t_p = 20\text{ }\mu\text{s}$	$T_J = 150\text{ }^{\circ}\text{C}$	4	A
$P_{G(AV)}$	Average gate power dissipation		$T_J = 150\text{ }^{\circ}\text{C}$	1	W
T_{stg}	Storage junction temperature range			-40 to +150	$^{\circ}\text{C}$
T_J	Operating junction temperature range			-40 to +150	$^{\circ}\text{C}$

Table 3: Electrical characteristics ($T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

Symbol	Test conditions	Quadrant		Value		Unit
				T835H	T850H	
$I_{GT}^{(1)}$	$V_D = 12\text{ V}$, $R_L = 33\text{ }\Omega$	I - II - III	Max.	35	50	mA
V_{GT}			Max.	1.0		V
V_{GD}	$V_D = V_{DRM}$, $R_L = 3.3\text{ k}\Omega$	I - II - III	Min.	0.15		V
$I_H^{(2)}$	$I_T = 500\text{ mA}$		Max.	35	75	mA
I_L	$I_G = 1.2 \times I_{GT}$	I - III	Max.	50	60	mA
		II		80	110	
$dV/dt^{(2)}$	$V_D = 2/3 \times V_{DRM}$, gate open	$T_J = 150\text{ }^{\circ}\text{C}$	Min.	1000	1500	V/ μs
$(di/dt)_C^{(2)}$	Without snubber	$T_J = 150\text{ }^{\circ}\text{C}$	Min.	11	14	A/ms

Notes:

⁽¹⁾minimum I_{GT} is guaranteed at 20% of I_{GT} max.

⁽²⁾for both polarities of A2 referenced to A1.

Table 4: Static characteristics

Symbol	Test conditions			Value	Unit
$V_T^{(1)}$	$I_{TM} = 11 \text{ A}$, $t_p = 380 \text{ } \mu\text{s}$	$T_j = 25 \text{ } ^\circ\text{C}$	Max.	1.5	V
$V_{T0}^{(1)}$	Threshold voltage	$T_j = 150 \text{ } ^\circ\text{C}$	Max.	0.80	V
$R_d^{(1)}$	Dynamic resistance	$T_j = 150 \text{ } ^\circ\text{C}$	Max.	52	m Ω
$I_{DRM} / I_{RRM}^{(2)}$	$V_{DRM} = V_{RRM}$	$T_j = 25 \text{ } ^\circ\text{C}$	Max.	5	μA
		$T_j = 150 \text{ } ^\circ\text{C}$	Max.	3.1	mA
	$V_D/V_R = 400 \text{ V}$ (at peak mains voltage)	$T_j = 150 \text{ } ^\circ\text{C}$	Max.	2.5	
	$V_D/V_R = 200 \text{ V}$ (at peak mains voltage)	$T_j = 150 \text{ } ^\circ\text{C}$	Max.	2.0	

Notes:⁽¹⁾for both polarities of A2 referenced to A1⁽²⁾ $t_p = 380 \text{ } \mu\text{s}$

Table 5: Thermal parameters

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case (AC)	D ² PAK, TO-220AB	1.85	$^\circ\text{C/W}$
		TO-220AB Ins.	3.7	
$R_{th(j-a)}$	Junction to ambient ($S_{cu} = 1 \text{ cm}^2$)	D ² PAK	45	
	Junction to ambient	TO-220AB, TO-220AB Ins.	60	

1.1 Characteristics (curves)

Figure 1: Maximum power dissipation versus on-state RMS current (full cycle)

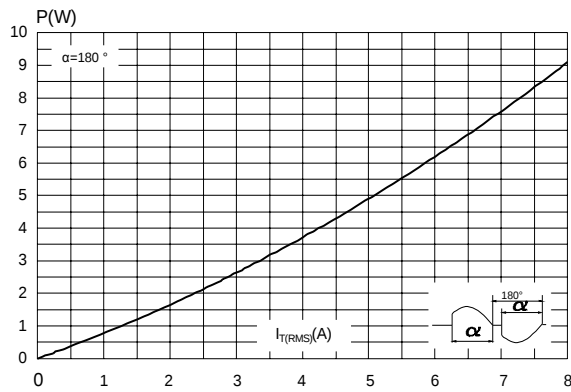


Figure 2: On-state RMS current versus case temperature (full cycle)

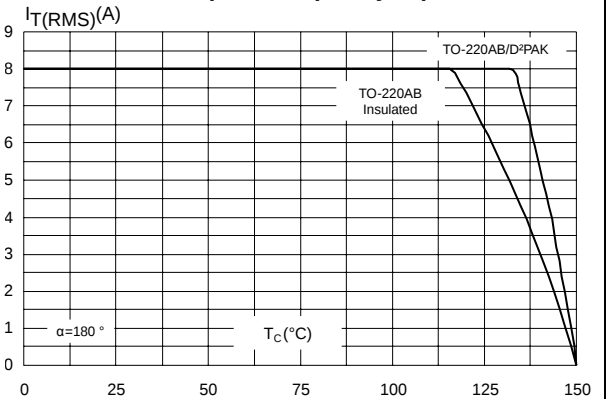


Figure 3: On-state RMS current versus ambient temperature

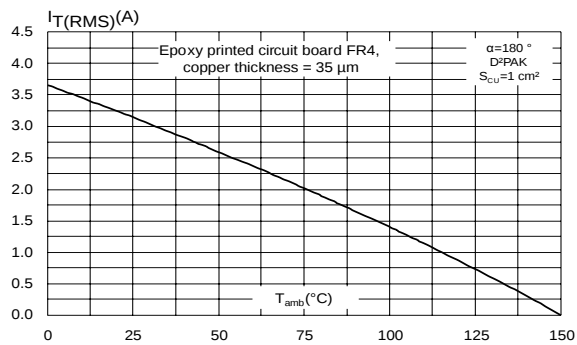


Figure 4: Variation of thermal impedance versus pulse duration

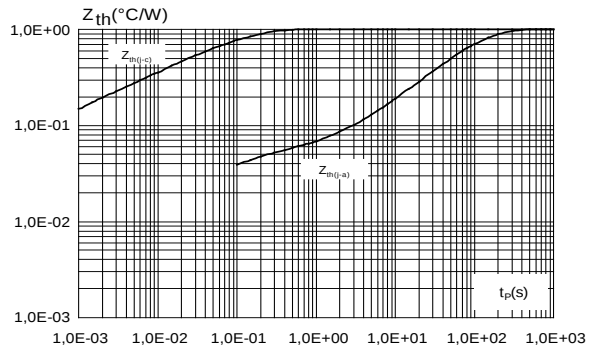


Figure 5: On-state characteristics (maximum values)

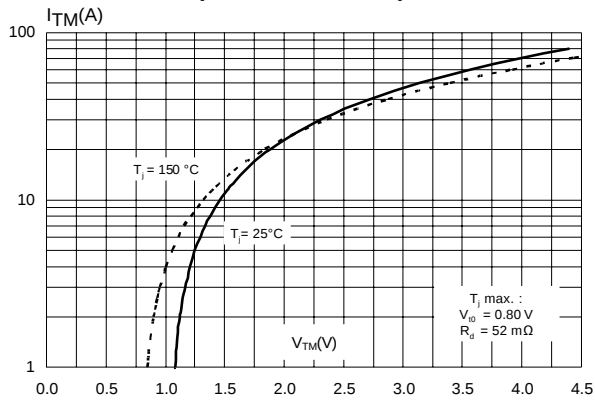


Figure 6: Surge peak on-state current versus number of cycles

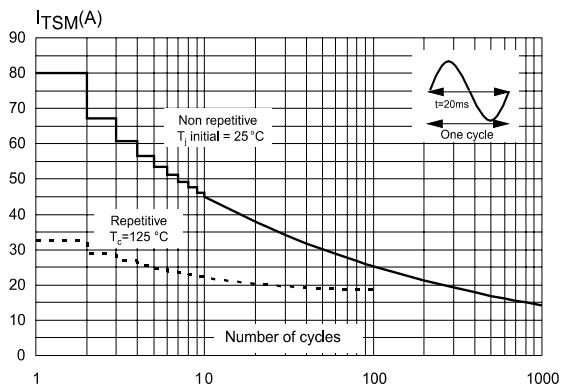
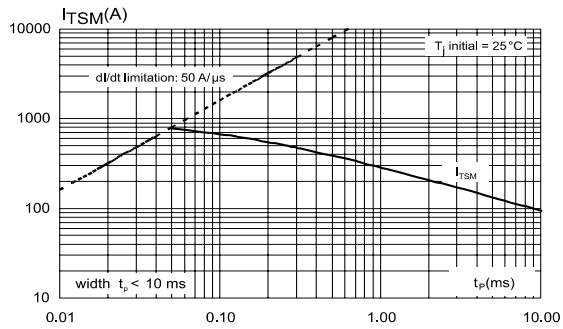
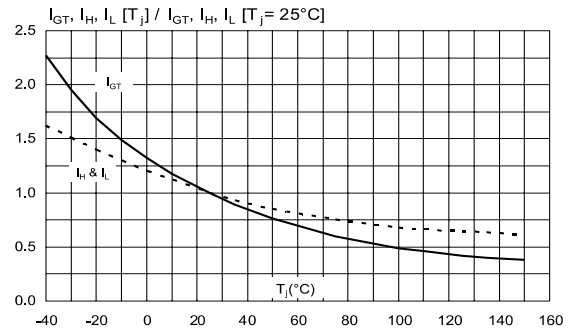
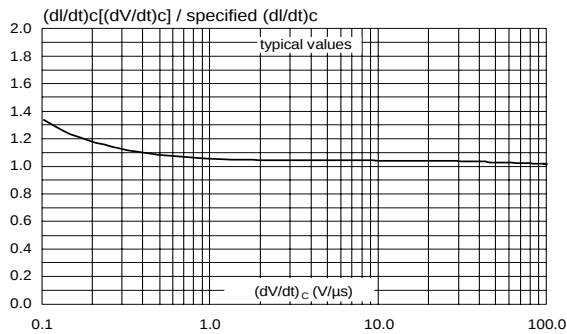
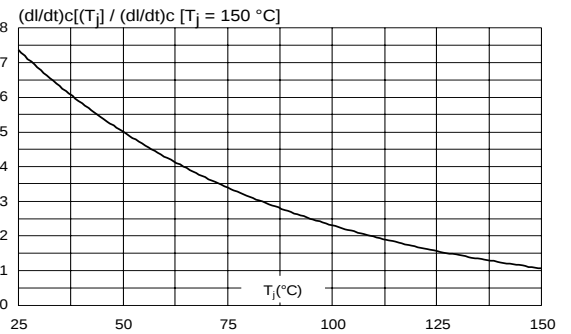
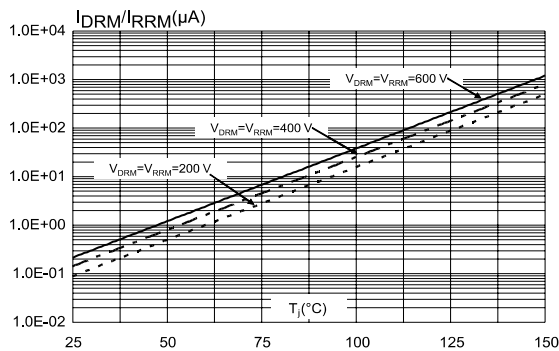
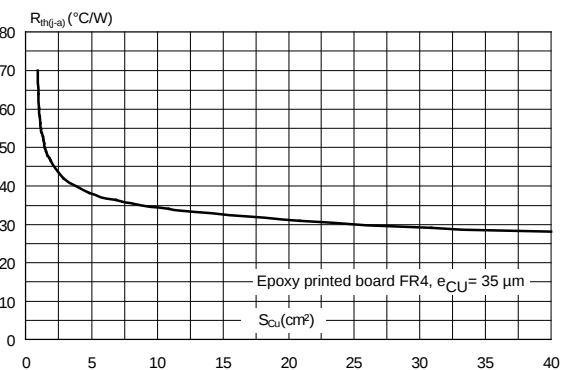


Figure 7: Non-repetitive surge peak on-state current for a sinusoidal pulse**Figure 8: Relative variation of I_{GT} , I_H , I_L versus junction temperature (typical values)****Figure 9: Relative variation of critical rate of decrease of main current $(dI/dt)_c$ versus reapplied $(dV/dt)_c$** **Figure 10: Relative variation of critical rate of decrease of main current versus junction temperature****Figure 11: Leakage current versus junction temperature for different values of blocking voltage (typical values)****Figure 12: Variation of thermal resistance junction to ambient versus copper surface under tab**

2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

- Epoxy meets UL94, V0
- Lead-free package leads
- Cooling method: by conduction (C)

2.1 D²PAK package information

Figure 13: D²PAK package outline

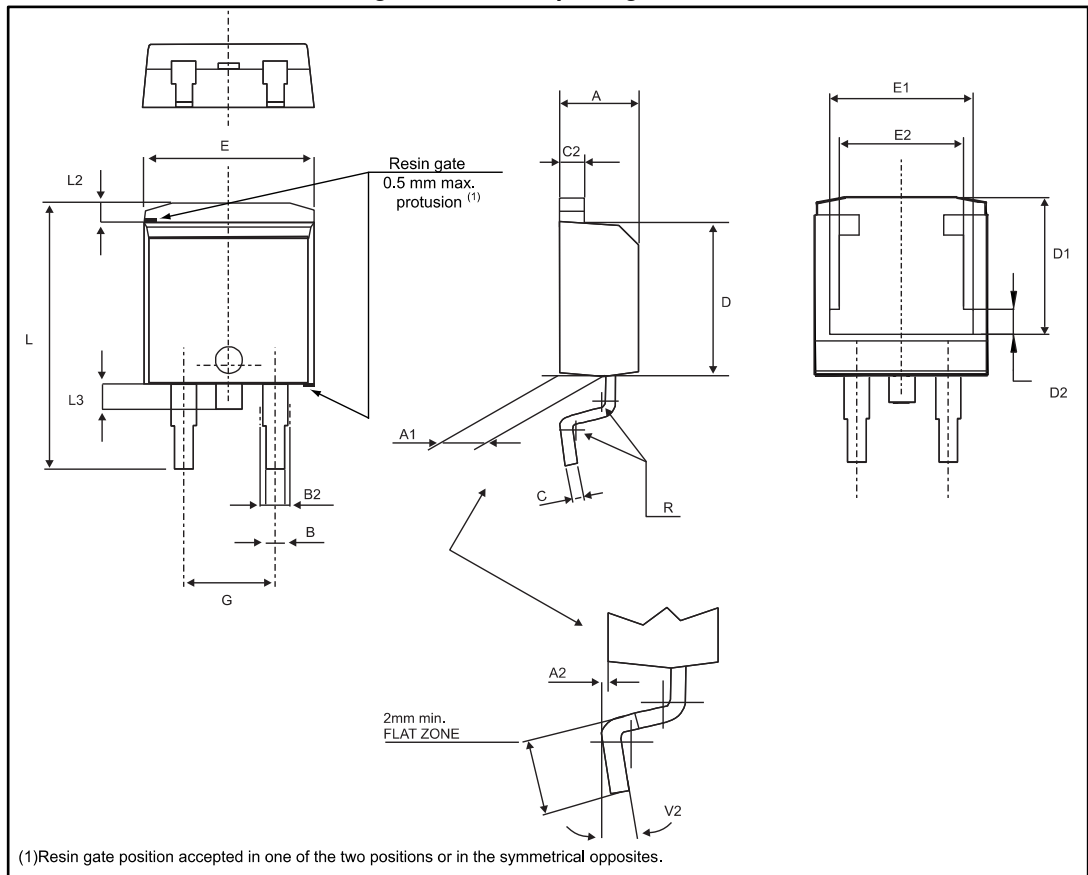
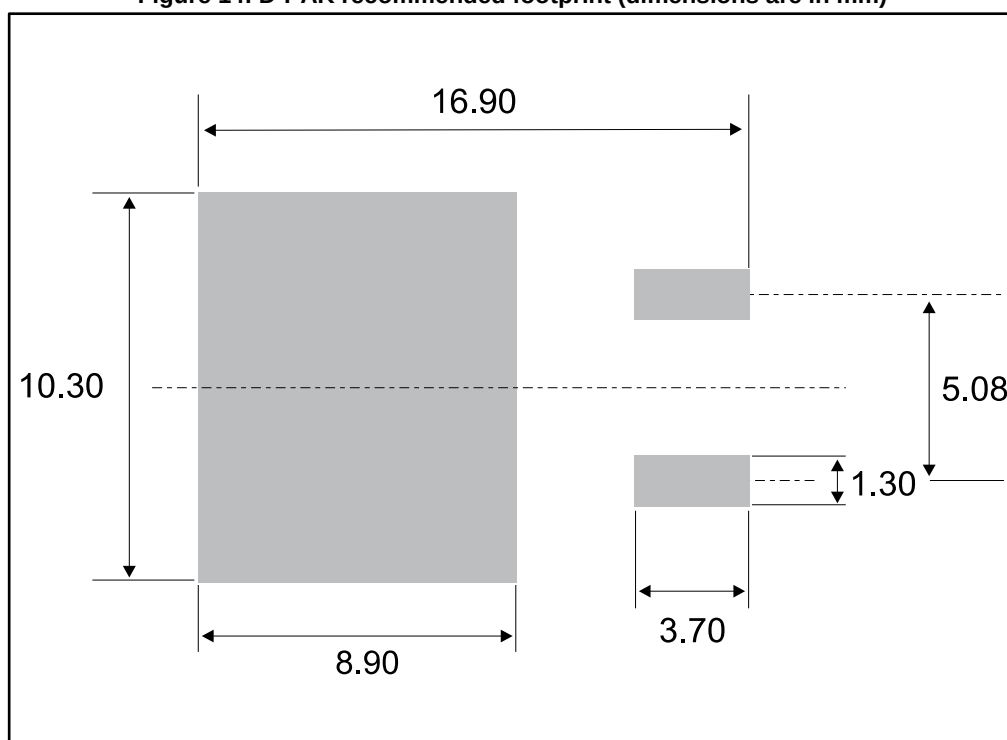


Table 6: D²PAK package mechanical data

Ref.	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.30		4.60	0.1693		0.1811
A1	2.49		2.69	0.0980		0.1059
A2	0.03		0.23	0.0012		0.0091
B	0.70		0.93	0.0276		0.0366
B2	1.25	1.40		0.0492	0.0551	
C	0.45		0.60	0.0177		0.0236
C2	1.21		1.36	0.0476		0.0535
D	8.95		9.35	0.3524		0.3681
D1	7.50		8.00	0.2953		0.3150
D2	1.30		1.70	0.0512		0.0669
E	10.00		10.28	0.3937		0.4047
E1	8.30		8.70	0.3268		0.3425
E2	6.85		7.25	0.2697		0.2854
G	4.88		5.28	0.1921		0.2079
L	15		15.85	0.5906		0.6240
L2	1.27		1.40	0.0500		0.0551
L3	1.40		1.75	0.0551		0.0689
R		0.40			0.0157	
V2	0°		8°	0°		8°

Notes:⁽¹⁾Dimensions in inches are given for reference only

Figure 14: D²PAK recommended footprint (dimensions are in mm)

2.2 TO-220AB (NIns. and Ins.) package information

Figure 15: TO-220AB (NIns. and Ins.) package outline

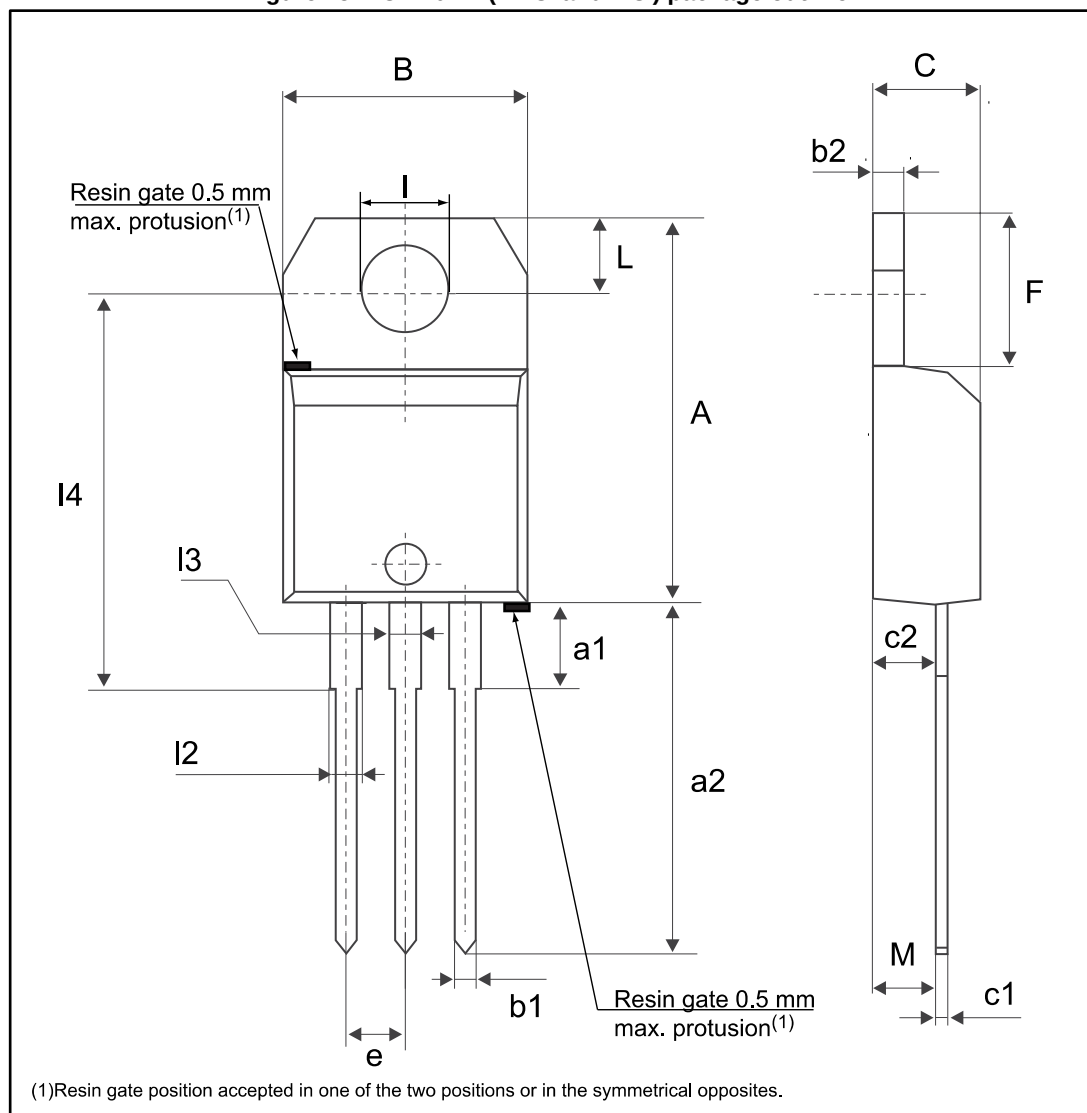


Table 7: TO-220AB (Nlns. and Ins.) package mechanical data

Ref.	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.5984		0.6260
a1		3.75			0.1476	
a2	13.00		14.00	0.5118		0.5512
B	10.00		10.40	0.3937		0.4094
b1	0.61		0.88	0.0240		0.0346
b2	1.23		1.32	0.0484		0.0520
C	4.40		4.60	0.1732		0.1811
c1	0.49		0.70	0.0193		0.0276
c2	2.40		2.72	0.0945		0.1071
e	2.40		2.70	0.0945		0.1063
F	6.20		6.60	0.2441		0.2598
I	3.73		3.88	0.1469		0.1528
L	2.65		2.95	0.1043		0.1161
l2	1.14		1.70	0.0449		0.0669
l3	1.14		1.70	0.0449		0.0669
l4	15.80	16.40	16.80	0.6220	0.6457	0.6614
M		2.6			0.1024	

Notes:⁽¹⁾Inch dimensions are for reference only.

3 Ordering information

Figure 16: Ordering information scheme

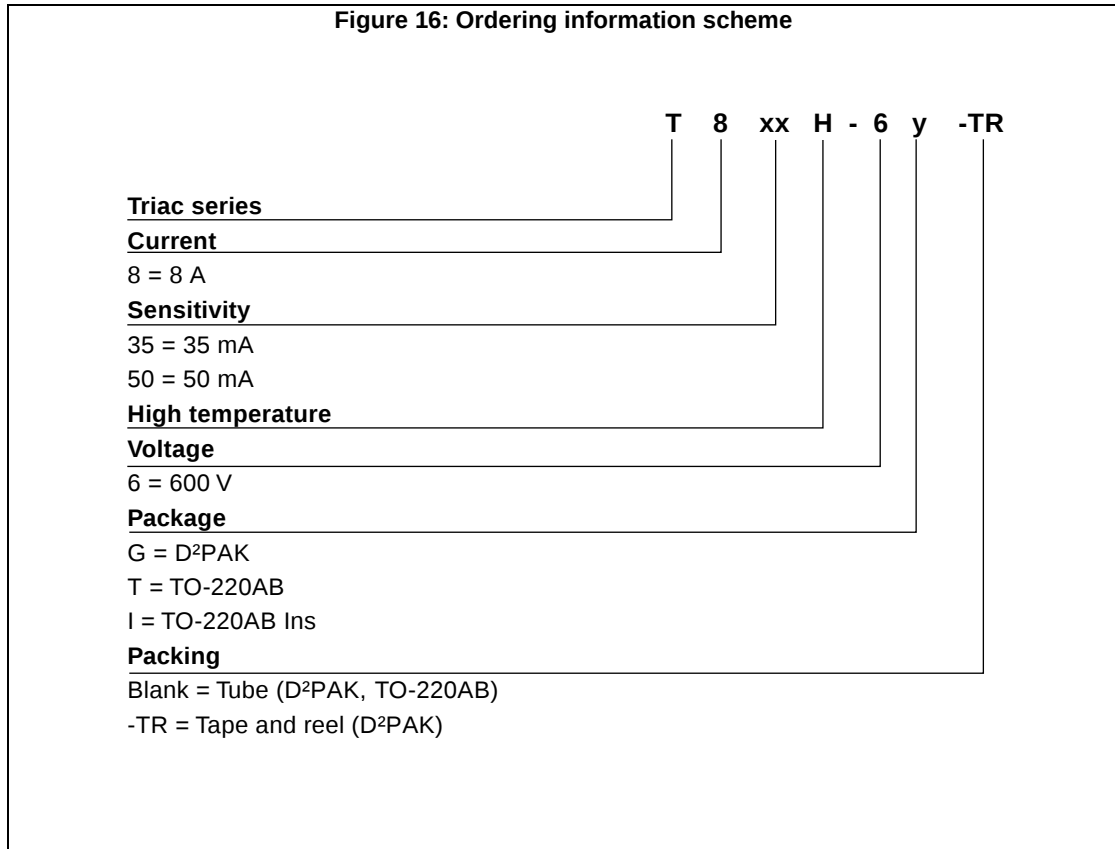


Table 8: Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
T8xxH-6G	T8xxH 6G	D ² PAK	1.5 g	50	Tube
T8xxH-6G-TR	T8xxH 6G	D ² PAK	1.5 g	1000	Tape and reel
T8xxH-6T	T8xxH 6T	TO-220AB	2.3 g	50	Tube
T8xxH-6I	T8xxH 6I	TO-220AB Ins.	2.3 g	50	Tube

4 Revision history

Table 9: Document revision history

Date	Revision	Changes
17-Apr-2007	1	First issue.
19-Sep-2011	2	Updated: <i>Features, Description, Figure 2, Table 2 and 4.</i>
30-Mar-2017	3	Minor text changes. Updated Table 4: "Static characteristics" and Figure 7: "Non-repetitive surge peak on-state current for a sinusoidal pulse" .

IMPORTANT NOTICE – PLEASE READ CAREFULLY

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2017 STMicroelectronics – All rights reserved